#### GUIDANCE FOR ABSTRACT PREPARATION

Author A.B., Author C.D.<sup>(1)</sup>, Author E.F.<sup>(2)</sup> etc. Full title of organization, postal and e-mail addresses <sup>(1)</sup>Full title of organization, postal and e-mail addresses <sup>(2)</sup>Full title of organization, postal and e-mail addresses

Abstracts are to be prepared in English and should not exceed one page in length (A4 format, 29.7 cm × 21 cm), including tables and figures, in the Microsoft Word format, versions 6.0-7.0.

The abstract title should be typed in capital letters using the Times New Roman bold font, 14 point, and centred in the first line over the width of two columns. The following line is to be left blank. Next, the names and initials of authors should be typed in 12-point bold font, and centred. The name of the presenting author should be underlined.

Next, the full name, postal address, and the email address of the institution (using a separate line for each institution) should be typed with 12-point font and centred. The following line is to be left blank.

The two-column text of abstract should be typed with 11-point font using single spacing. Margins: 3 cm top and 2 cm bottom, left, and right. Use 1 cm spacing between the columns.

High-quality illustrations should be prepared as JPG or BMP files. References should be numbered consecutively (numerals in square brackets) throughout the text and put together in a reference list at the end of abstract.

#### **INFORMATION ABOUT AUTHORS**

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Phone, Fax:		
E-mail:		

## Contacts with Ukrainian National Organization Group:

Institute for Problems of Materials Science of NASU, "MEE-2012"

3 Krzhyzhanovsky St.

Kiev, 03680, Ukraine

Chernyshev Leonid, Fedorova Nataliia

Phone/Fax: (38044) 424-2073 E-mail: chern@ipms.kiev.ua,

umrs2004@ukr.net

National Academy of Sciences of Ukraine (NASU)
Russian Academy of Sciences (RAS)
National Academy of Sciences of Belarus (NASB)
Ukrainian Materials Research Society
Frantsevich Institute for Problems of Materials Science of NASU
Institute for High Temperatures of RAS
Bauman Moscow State Technical University
Lykov Institute for Heat and Mass Exchange of NASB
INTEM LTD (Ukraine)

## SEVENTH INTERNATIONAL CONFERENCE

«Materials and Coatings for Extreme Performances: Investigations, Applications, Ecologically Safe Technologies for Their Production and Utilization»

### FIRST ANNOUNCEMENT









National Information Point of 7 Framework Program

24-28 September, 2012

Katsively, House of Scientists of NASU, Crimea, Ukraine

#### ORGANIZING COMMITTEE

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Konstantinova T. —
Ukraine, Prof.
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Movchan B. — Ukraine, full
member of NASU
Nakamura T. — Japan, Prof.
Potapov A. — Ukraine, Dr.
Prikhna T. — Ukraine,
corres. member of NASU

Rabier J. – France. Prof.
Reznik S. – Russia, Prof.
Sanin A. – Ukraine, Prof.
Smertenko P. – EUREKA –
Ukraine, Dr
Solntsev K.– Russia, full
member of RAS
Ternovoi Yu. – Ukraine, Prof.
Tikhii V. – Ukraine, Prof.
Timofeev A. – Russia, Prof.
Timoshenko V.I. – Ukraine,
cores. member of NASU
Timoshenko V.P. – Russia,
Prof.
Zalite I. – Latvia, Dr.

#### PROBLEMS COVERED BY CONFERENCE

(Title of Sessions)

- A. Principles of designing materials and coatings for operation in hazard conditions.
- B. Scientific fundamentals and computer models for the processes of manufacturing materials and coatings for operation in hazard conditions.
- C. Advanced technologies for production and joining materials and products for operation in hazard conditions.
- D. Structure and properties of materials and coatings for operation in hazard conditions.
- E. Special Session "Thermal Barrier Coatings".
- F. Experimental data obtained from performance of materials and coatings in on location hazard conditions.
- G. Potential and contemporary technologies for recycling industrial waste aimed to production structural, heat-insulative, facing and other materials.
- H. Scientific, organization and information problems of cooperation between scientists in the field of materials science.
- I. Round Table "Effective transfer of technology is catalyst of society innovation development".

#### **GENERAL INFORMATION**

Crimean Conferences will be hold in seventh time with these topics. Conferences in Crimea concentrate attention of participants on one of the most important fields of materials science, namely, science and technology of materials (including nano- and "smart") for hazard conditions service; high and cryogenic temperatures, aggressive environments, complex and

The discussions on the problems concerning ecology, recycling production waste and material that exhausted their resources are of great scientific and practical importance. The actuality c proposed problems for discussion is confirmed by the fact that more than 250 specialists too participation in each previous conferences. The Organizing Committee believes that th number of conference participants will increase in 2012, and the time for conference holding the "velvet" season in Crimea - will promote the successful work of conference. Th temperature of air that season is +23-26 °C and sea water +20-22 °C.

The Conference will take place and participants be accommodated at House of Scientists of NASU that is located in settlement Katsiveli at the very beach of Black Sea. At this center there are rooms equipped with balconies, TV, refrigerators. You may spend free time a excellent beach equipped with chaise-longues and tents. The conference participants will have three meals a day.

The pension has one-bed and two-beds comfortable rooms. The full financial informatio about conference participation will be presented in the second announcement. Approximatel accommodation is about \$60-65. Tentatively the conference fee will be €300. The discount wibe offered for students and post-graduates.

The conference participants can reach conference place from the capital of Crimes Sympheropol city by bus or taxi. This town has International airport. Travel time to House of Scientists of NASU is about 100–110 min.

#### REGULATION OF CONFERENCE

The conference will be organized as sessions.

Plenary session will be held at the first day of conference, and it will be devoted to both problematic and survey presentations selected by Organizing Committee. So the participant are requested to inform if they intend to make such presentation.

The participants are requested to choose the session title and point out it in the information attached to submission, and also kind of presentation, which is preferred — oral or poster. The topics of round tables are not covered by list of scientific areas in this announcement, they also could be proposed by participants.

The official languages of conference will be Russian and English.

Abstracts up to one page prepared in accordance with Instruction will be published as at English version and disseminated among participants before conferences start.

#### IMPORTANT DEADLINES

Submission of abstracts
-15.05.2012
Dissemination of second information issue
-30.06.2012

Fee payment from 01.07 till 01.09.2012

Information about the Conference will be published at the following web-sites

#### INFORMATION ABOUT AUTHORS

#### Title:

Optoelectronic temperature sensors based on Ge-As-Se chalcogenide glassy semiconductors for operation in radiation-hazard conditions

#### Index of session:

D. Structure and properties of materials and coatings for operation in hazard conditions.

Form of report:

Oral

Poster X

Authors:

(1) Surname: Chalyy Christian Name: Dmytro

Organization title: Lviv State University of Vital Activity Safety

Position: PhD student

Postal address: 35 Kleparivska str., Lviv, Ukraine

Phone, Fax: 097 7025920

E-mail: dima-docent@mail.ru

(2) Surname: Shpotyuk Christian Name: Mykhaylo

Organization title: Lviv Polytechnic National University

Position: Junior Researcher

Postal address: 12 Bandery str., Lviv, Ukraine

Phone, Fax: 068 5020566

E-mail: shpotyukmy@yahoo.com

(3) Surname: Ubizskii Christian Name: Sergii

Organization title: Lviv Polytechnic National University

Position: Head of Laboratory

Postal address: 12 Bandery str., Lviv, Ukraine

Phone, Fax: 050 1881501
E-mail: crystal@lp.edu.ua

# OPTOELECTRONIC TEMPERATURE SENSORS BASED ON Ge-As-Se CHALCOGENIDE GLASSY SEMICONDUCTORS FOR OPERATION IN RADIATION-HAZARD CONDITIONS

Chalyy D.O., Shpotyuk M.V.(1), Ubizskii S.B.(1)

Lviv State University of Vital Activity Safety, 35 Kleparivska str., Lviv, Ukraine

(1) Lviv Polytechnic National University, 12 Bandery str., Lviv, Ukraine

shpotyukmy@yahoo.com

Environment optoelectronic sensors based on optical fibers are known to be one of the most perspective sensing devices revealed a number of essential advantages over known counterparts, such as immunity to electromagnetic interference, lightweight, small size, high sensitivity, large bandwidth and ease in implementing multiplexed or distributed sensors, etc. Temperature, pressure and mechanical strains are most widely control parameters measured with fiber-based optical sensors (FBOS). But despite achieved progress in the last years, the development of high-reliable FBOS capable to work in the hazard radiation environment is an actual problem up to now. Mechanical stress measurements for structural integrity monitoring of reactor containment buildings, chemical control of nuclear waste tanks and radiation monitoring of geological waste disposals are only few examples of such industrial applications related to environmentally-hazard extreme conditions.

The temperature T-monitoring within nuclear reactors is one of the most promising areas, where FBOS can be successfully used alternatively to conventional sensing devices such as Pt-resistance thermometers. This sensor contains a semiconductor crystal (T-sensitive functional element) like to GaAs coated with a dielectric mirror, the both elements being epoxyied to the fiber tip. The fiber made of pure silica glass is used as optical waveguard, the whole construction being protected and mechanically strengthened with Teflon tubing. The main operation principle

of this T-measuring FBOS is grounded on a well-known negative temperature coefficient dependence of semiconductor bandgap: the measuring of fundamental optical absorption edge position yields the environment temperature.

However, this kind of T-measuring FBOS is hardly operated in the hazard radiation conditions accompanied radiation-induced because of structural damages hided the real value of pure Trelated effect. Thus, in crystalline GaAs, the fundamental optical absorption edge depends on both radiation defects and ambient temperature in a too complicated manner to provide reliable Tmeasurements. This important problem can be successfully resolved by corresponding choice of T-sensitive functional semiconductor element possessing a great T-induced shift of fundamental optical absorption edge combined with relatively small or even negligible under-margin radiation sensitivity.

In this work we report on the possibility of application of chalcogenide semiconductors of Ge-As-Se family as active media for T-measuring FBOS. Temperature and radiation-induced changes of optical transmission in the fundamental optical absorption edge region Quasi-linear temperature studied. dependences of the optical characteristics were observed through the whole investigated range of temperatures (from the room temperature to the temperature). transition Additionally, glass radiation-induced negligible changes were recorded.